



60V NPN LOW SATURATION TRANSISTOR

Description

Advanced process capability has been used to maximise the performance of this 60V, NPN transistor. The U-DFN2020-3 (Type B) package offers lower profile and the derating up to +175°C allows higher dissipation for applications where power density is of utmost importance.

Features

- BV_{CEO} > 60V
- I_C = 4A Continuous Collector Current
- Low Saturation Voltage (100mV Max @1A)
- $R_{SAT} = 60 \text{m}\Omega$ for a Low Equivalent On-Resistance
- hFE Specified up to 6A for High Current Gain Hold Up
- **Tighter Gain Specification**
- Low Profile 0.6mm High Package for Thin Applications
- R_{θJA} Efficient, 60% Lower than SOT23
- 4mm² Footprint, 50% Smaller than SOT23
- Rated +175°C Ideal for High Temperature Environment
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DXTN10060DFJBQ is suitable for automotive applications requiring specific change control and is AEC-Q101 qualified, is PPAP capable, and is manufactured in IATF16949:2016 certified facilities.

Mechanical Data

- Case: U-DFN2020-3
- Nominal Package Height: 0.6mm
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu, Solderable per MIL-STD-202,
- Weight: 0.01 grams (Approximate)

Applications

- **Automotive Systems**
 - MOSFET Gate Driving
 - **DC-DC Converters**
 - Motor Control
 - **Power Switches**

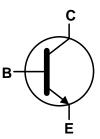
U-DFN2020-3 (Type B)



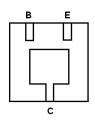




Bottom View



Device Symbol



Bottom View Pin-Out

Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel	
DXTN10060DFJBQ-7	Automotive	2L6	7	8	3,000	
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.						

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- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain < 900ppm bromine, < 900ppm chlorine (< 1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

U-DFN2020-3 (Type B)



2L6 = Product Type Marking Code Y = Year: 0~9 W = Week: A~Z: 1~26 Week; a~z: 27~52 Week; z Represents 52 and 53 Week X = A~Z: Internal Code



Absolute Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Parameter		Symbol	Limit	Unit	
Collector-Base Voltage		V _{CBO}	100		
Collector-Emitter Voltage		V _{CEO}	60	V	
Emitter-Base Voltage		V_{EBO}	8		
Peak Pulse Current		I _{CM}	6		
Continuous Collector Current (Note 5) (Note 6)		_	4	1	
		Ic	4.3	A	
Base Current		I _B	1		

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)		1.8 12	W	
Linear Derating Factor	(Note 6)	P _D	2.94 19.6	mW/°C	
Thermal Resistance, Junction to Ambient	(Note 5)	D	83	°C/W	
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	51		
Thermal Resistance, Junction to Lead	(Note 7)	$R_{ heta JL}$	16.8		
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +175	°C		

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

- 5. For a device mounted with the exposed collector pad on 31mm × 31mm (10cm²) 1oz copper that is on a single sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state. The entire exposed collector pad is attached to the heatsink.

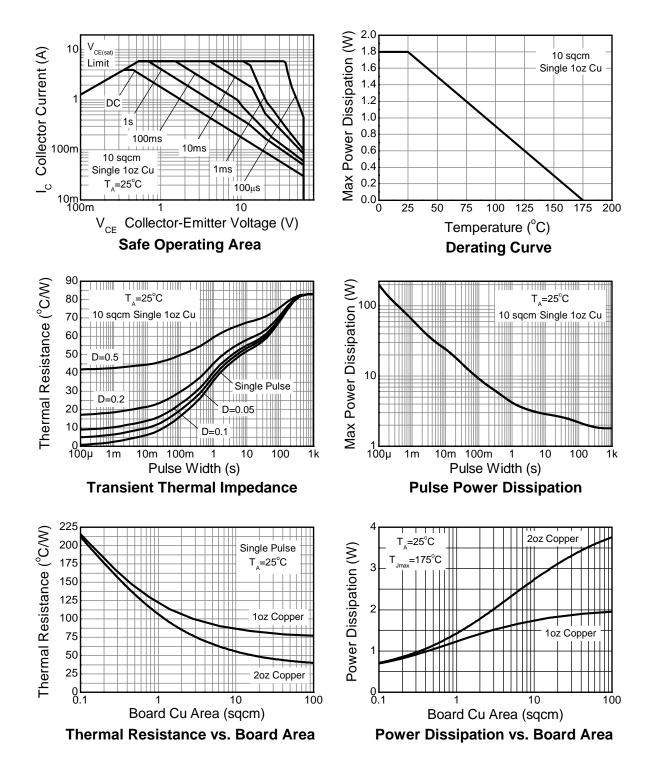
 6. Same as Note 5, except the device is measured at t ≤ 5s.

 7. Thermal resistance from junction to solder-point (on the exposed collector pad).

- 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





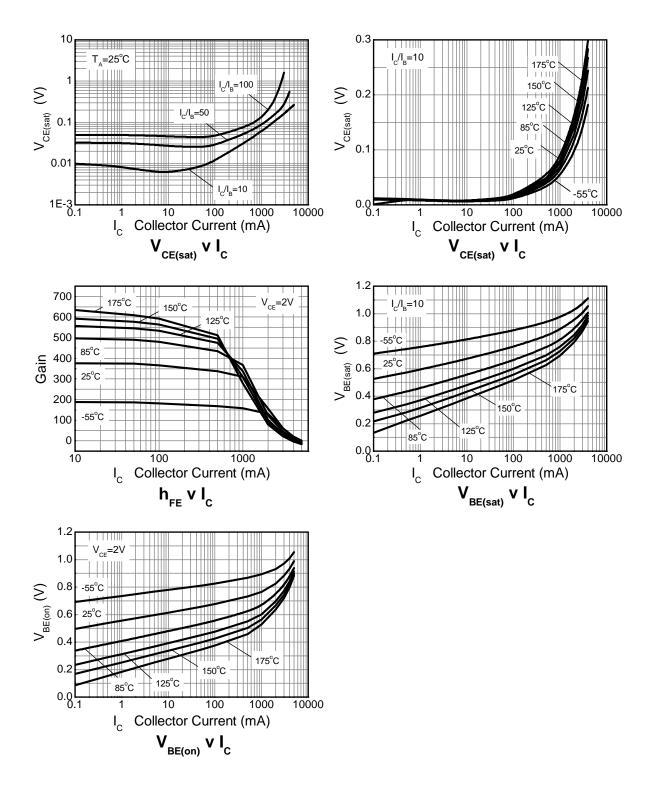
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	150	187	_	V	$I_{C} = 100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	60	66	_	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	8	9	_	V	$I_E = 100 \mu A$
Collector Cutoff Current	Ісво	_	2	100	nA	V _{CB} = 120V
Emitter Cutoff Current	I _{EBO}	_	2	100	nA	V _{EB} = 7V
Collector Emitter Cutoff Current	Ices	_	2	100	nA	V _{CES} = 48V
Static Forward Current Transfer Ratio (Note 9)	hFE	250 340 250 140 20	444 425 363 205 40	550 500 — — —	_	$\begin{split} &I_{C} = 10\text{mA}, \ V_{CE} = 2\text{V} \\ &I_{C} = 200\text{mA}, \ V_{CE} = 2\text{V} \\ &I_{C} = 1\text{A}, \ V_{CE} = 2\text{V} \\ &I_{C} = 2\text{A}, \ V_{CE} = 2\text{V} \\ &I_{C} = 6\text{A}, \ V_{CE} = 2\text{V} \end{split}$
Collector-Emitter Saturation Voltage (Note 9)	V _{CE(sat)}		12 70 125 150 200 240	20 100 160 200 300 320	mV	$\begin{split} &I_C = 0.1 \text{A}, I_B = 10 \text{mA} \\ &I_C = 1 \text{A}, I_B = 50 \text{mA} \\ &I_C = 1 \text{A}, I_B = 10 \text{mA} \\ &I_C = 2 \text{A}, I_B = 50 \text{mA} \\ &I_C = 3 \text{A}, I_B = 100 \text{mA} \\ &I_C = 4 \text{A}, I_B = 200 \text{mA} \end{split}$
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(on)}		0.94	1.00	V	$I_C = 4A$, $V_{CE} = 2V$
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	_	1.00	1.07	V	$I_C = 4A$, $I_B = 200mA$
Output Capacitance	C _{obo}	_	14	_	pF	$V_{CB} = 10V, f = 1MHz$
Transition Frequency	f _T	125	_	_	MHz	V _{CE} = 10V, I _C = 50mA, f = 100MHz
Turn-On Time	t _{ON}	_	200	_	ns	V _{CC} = 10V, I _C = 1A
Turn-Off Time	t _{OFF}	_	700	_	ns	$I_{B1} = -I_{B2} = 10 \text{mA}$

Note: 9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

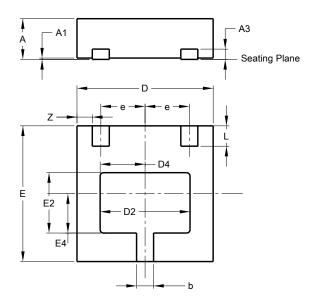




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2020-3 (Type B)

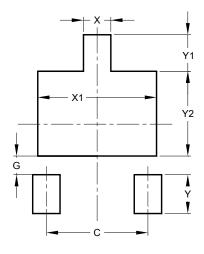


U-DFN2020-3 (Type B)						
Dim	Min	Max	Тур			
Α	0.57	0.63	0.60			
A1	0.00	0.05	0.02			
А3			0.152			
b	0.20	0.30	0.25			
D	1.950	2.075	2.00			
D2	1.22	1.42	1.32			
D4	0.56	0.76	0.66			
E	1.950	2.075	2.00			
E2	0.79	0.99	0.89			
E4	0.48	0.68	0.58			
е		_	0.65			
L	0.25	0.35	0.30			
Z			0.225			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2020-3 (Type B)



Dimensions	Value		
Dillielisions	(in mm)		
С	1.300		
G	0.240		
Х	0.350		
X1	1.520		
Υ	0.500		
Y1	0.470		
Y2	1.090		



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